

isc Silicon NPN Power Transistor

2SC4108

DESCRIPTION

- · High Collector-Emitter Breakdown Voltage-
- : V_{(BR)CEO}= 400V(Min)
- · High Switching Speed
- Wide Area of Safe Operation
- · Minimum Lot-to-Lot variations for robust device performance and reliable operation

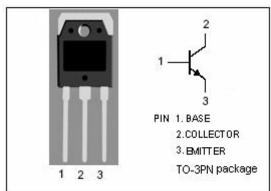
APPLICATIONS

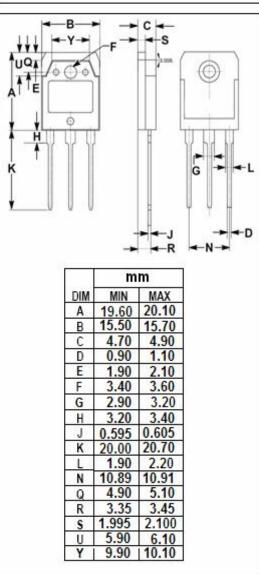


· Designed for switching regulator and general purpose applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	500	V	
V _{CEO}	Collector-Emitter Voltage 400		V	
V _{EBO}	Emitter-Base voltage	7	V	
Ic	Collector Current-Continuous	12	А	
Ісм	Collector Current-Peak	25	А	
I _B	Base Current-Continuous	4	А	
Pc	Collector Power Dissipation @ Tc=25°C	100	W	
	Collector Power Dissipation @ T _a =25°C	2.5		
TJ	Junction Temperature	150	°C	
T _{stg}	Storage Temperature Range	-55~150	°C	







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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

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SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CBO}	Collector-Base Breakdown Voltage	I _C = 1mA; I _E = 0	500			V
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 10mA; R _{BE} = ∞	400			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 1m A; I _C = 0	7			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 8A; I _B = 1.6A			0.8	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 8A; I _B = 1.6A			1.5	V
Ісво	Collector Cutoff Current	V _{CB} = 400V ; I _E = 0			10	μА
I _{ЕВО}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0			10	μ А
h _{FE-1}	DC Current Gain	I _C = 1.6A; V _{CE} = 5V	15		50	
h _{FE-2}	DC Current Gain	I _C = 8A; V _{CE} = 5V	10			
h _{FE-3}	DC Current Gain	I _C = 10mA ; V _{CE} = 5V	10			
f⊤	Current-Gain—Bandwidth Product	I _C = 1.6A; V _{CE} = 10V		20		MHz
Сов	Output Capacitance	I _E = 0; V _{CB} = 10V; f _{test} = 1.0MHz		160		pF
Switching T	imes				1	
ton	Turn-on Time				0.5	μ s
t _{stg}	Storage Time	I _C = 10A, I _{B1} = 2A; I _{B2} = -4A R _L = 20 Ω; V _{CC} = 200V			2.5	μ S
tf	Fall Time				0.3	μs

♦ h_{FE-1} Classifications

L	М	N
15-30	20-40	30-50

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